

N-Channel Silicon MOSFET

ECH8604



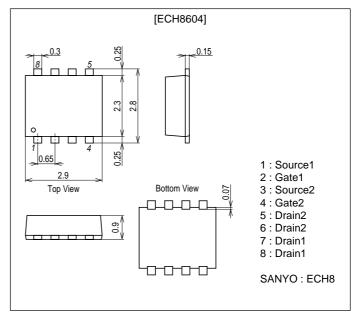
Load Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive

Package Dimensions

unit : mm 2206A



Specifications

Absolute Maximum Ratings at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | Unit |
|-----------------------------|--------|--|-------------|------|
| Drain-to-Source Voltage | VDSS | | 20 | V |
| Gate-to-Source Voltage | VGSS | | ±10 | V |
| Drain Current (DC) | ID | | 6 | Α |
| Drain Current (Pulse) | IDP | PW≤10μs, duty cycle≤1% | 40 | Α |
| Allowable Power Dissipation | PD | Mounted on a ceramic board (900mm²X0.8mm)1unit | 1.3 | W |
| Total Dissipation | PT | Mounted on a ceramic board (900mm²X0.8mm) | 1.5 | W |
| Channel Temperature | Tch | | 150 | °C |
| Storage Temperature | Tstg | | -55 to +150 | °C |

Electrical Characteristics at Ta=25°C

| Parameter | Symbol | Conditions | Ratings | | | Unit |
|-----------------------------------|----------|---|---------|-----|-----|-------|
| | | | min | typ | max | Offic |
| Drain-to-Source Breakdown Voltage | V(BR)DSS | I _D =1mA, V _G S=0 | 20 | | | V |
| Zero-Gate Voltage Drain Current | IDSS | V _{DS} =20V, V _{GS} =0 | | | 1 | μΑ |
| Gate-to-Source Leakage Current | IGSS | VGS=±8V, VDS=0 | | | ±10 | μΑ |
| Cutoff Voltage | VGS(off) | V _{DS} =10V, I _D =1mA | 0.5 | | 1.3 | V |

Marking: KE Continued on next page.

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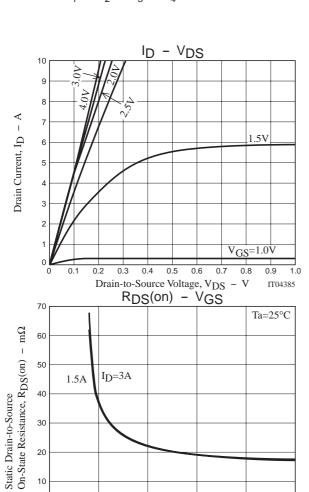
| Parameter | Symbol | Conditions | Ratings | | | Unit |
|--|-----------------------|--|---------|------|-----|------|
| | | | min | typ | max | Unit |
| Forward Transfer Admittance | yfs | V _{DS} =10V, I _D =3A | 7 | 10 | | S |
| Static Drain-to-Source On-State Resistance | R _{DS} (on)1 | ID=3A, VGS=4V | | 22 | 30 | mΩ |
| | RDS(on)2 | ID=1.5A, VGS=2.5V | | 30 | 44 | mΩ |
| Input Capacitance | Ciss | V _{DS} =10V, f=1MHz | | 700 | | pF |
| Output Capacitance | Coss | V _{DS} =10V, f=1MHz | | 300 | | pF |
| Reverse Transfer Capacitance | Crss | V _{DS} =10V, f=1MHz | | 150 | | pF |
| Turn-ON Delay Time | t _d (on) | See specified Test Circuit. | | 19 | | ns |
| Rise Time | t _r | See specified Test Circuit. | | 134 | | ns |
| Turn-OFF Delay Time | t _d (off) | See specified Test Circuit. | | 90 | | ns |
| Fall Time | tf | See specified Test Circuit. | | 94 | | ns |
| Total Gate Charge | Qg | V _{DS} =10V, V _{GS} =10V, I _D =6A | | 23 | | nC |
| Gate-to-Source Charge | Qgs | V _{DS} =10V, V _{GS} =10V, I _D =6A | | 1.6 | | nC |
| Gate-to-Drain "Miller" Charge | Qgd | V _{DS} =10V, V _{GS} =10V, I _D =6A | | 3.6 | | nC |
| Diode Forward Voltage | V _{SD} | I _S =6A, V _{GS} =0 | | 0.84 | 1.2 | V |

Electrical Connection

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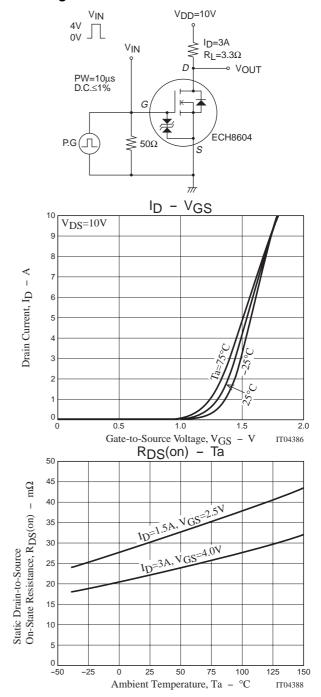
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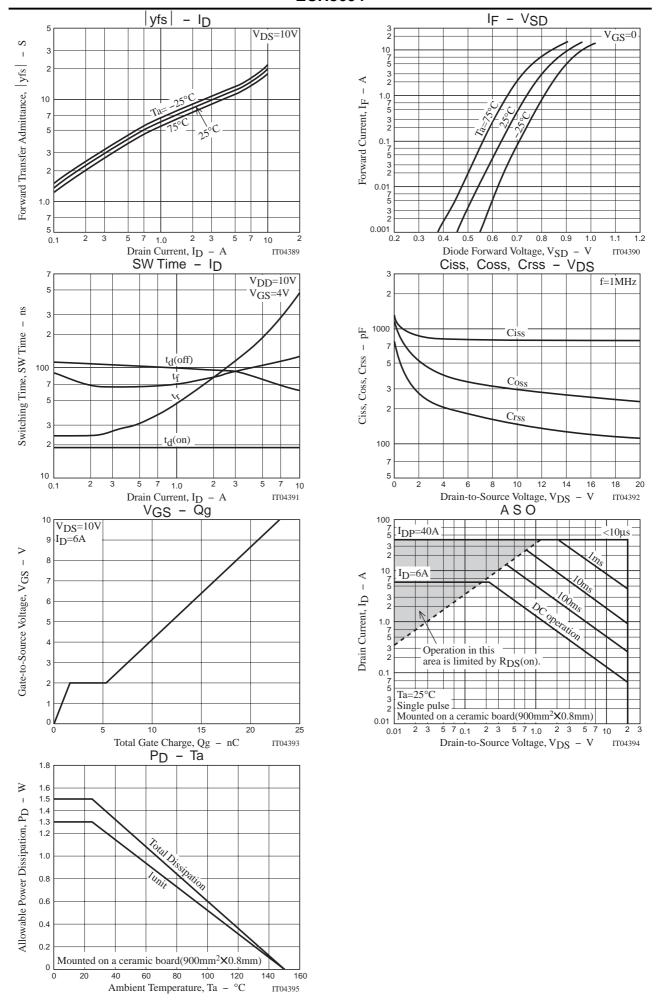
1: Source1 2 : Gate1 3: Source2 4 : Gate2 5 : Drain2 6: Drain2 7: Drain1 8: Drain1 (Top view)



Gate-to-Source Voltage, $V_{GS} - V$

Switching Time Test Circuit





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